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The first near-linear bis(amide) f-block complex: a blueprint for a high temperature single molecule magnet†

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We report the first near-linear bis(amide) 4f-block compound and show that this novel structure, if implemented with dysprosium(III), would have unprecedented single molecule magnet (SMM) properties with an energy barrier, U_{eff} , for reorientation of magnetization of 1800 cm^{-1} .

Since their initial discovery,¹ single molecule magnets (SMMs) have been lauded as candidates for high density data storage devices.² A major breakthrough in the field³ occurred in 2003 with the observation of SMM behavior in a monometallic $\{\text{TbPc}_2\}^-$ complex with an energy barrier, $U_{\text{eff}} = 230 \text{ cm}^{-1}$.⁴ The ensuing decade saw rapid growth in lanthanide SMMs⁵ with the U_{eff} barrier to magnetization reversal increased to 652 cm^{-1} for another derivative of $\{\text{TbPc}_2\}$,⁶ and 585 cm^{-1} for a polymetallic $\text{Dy}@(\text{Y}_4\text{K}_2)$ complex.⁷ The highest blocking temperature T_{B} (*i.e.* the temperature at which hysteresis is observed) was also increased to 14 K, *via* an $\text{N}_2^{3-\bullet}$ radical bridge in a $\{\text{Tb}_2\text{N}_2^{3-\bullet}\}$ complex.⁸

Although three of these milestones employ the Tb^{III} ion, by far the most utilized lanthanide ion in SMMs is Dy^{III} by virtue of its unique electronic structure.⁹ Apart from a radical-bridged $\{\text{Dy}_2\text{N}_2^{3-\bullet}\}$ complex,¹⁰ nearly all polymetallic Dy^{III} -based SMMs possess negligible interactions between magnetic spin centres, and instead rely on the single ion anisotropy of Dy^{III} (*i.e.* the local crystal field environment) to provide the barrier to the reversal of magnetization. Intra- or intermolecular interactions are often detrimental to the performance of Dy^{III} SMMs so that doping a small amount of the paramagnetic ion into a diamagnetic host lattice (usually the Y^{III} analogue) often results in an increased U_{eff} .⁷

An electrostatic model for the design of ideal ligand environments to exploit the maximal anisotropy of Dy^{III} has been postulated,^{11,12} and shown to be in good agreement with multi-configurational complete active space Self consistent field

(CASSCF) *ab initio* calculations¹² that are often employed to examine 4f complexes, pioneered by Chibotaru.^{7,13} Electrostatic approaches suggest that the optimal ligand environment to exploit the oblate spheroidal electron density of Dy^{III} is axial, where rigorously axial systems have the benefit of maintaining a single, unique quantization axis for the total angular momentum m_j states.¹⁴ A set of unadulterated m_j states implies that the probability of quantum tunnelling of the magnetization (QTM) is reduced, therefore increasing magnetic relaxation times.²

The simplest axial ligand environment is a linear two-coordinate complex with donor atoms exclusively on a single Cartesian axis; the U_{eff} barrier is so large for the $\{\text{Dy}_5\}$ and $\{\text{Dy}_4\text{K}_2\}$ alkoxide complexes⁷ because of the strongly axially repulsive crystal field potentials along the local z -direction of each Dy^{III} . Other compounds such as $[(\text{C}_8\text{H}_8)_2\text{Ln}]^-$ (ref. 15) or Cloke's bis(arene) lanthanide complexes¹⁶ are sometimes described as linear, but lack donor atoms directly on the axis. Linear 3d-metal compounds also show remarkable magnetic behaviour with very high U_{eff} values.¹⁷ A one coordinate lanthanide complex $[\text{DyO}]^+$ has been considered theoretically with a very large U_{eff} predicted,¹⁴ however such an entity is not chemically feasible.

Very low coordination numbers for 4f-ions are difficult to achieve as these are large, electropositive ions, which require a sterically demanding ligand. Such a pro-ligand $\text{HN}(\text{Si}^i\text{Pr}_3)_2$ was designed, and synthesised from ClSi^iPr_3 and $\text{LiHN}(\text{Si}^i\text{Pr}_3)_2$, and this was converted to the group 1 transfer agent $[\text{KN}(\text{Si}^i\text{Pr}_3)_2]$ with KH. Reacting two equivalents of $[\text{KN}(\text{Si}^i\text{Pr}_3)_2]$ with samarium(II) diiodide yields the mononuclear homoleptic bis(amide) complex, $[(^i\text{Pr}_3\text{Si})_2\text{N-Sm-N}(\text{Si}^i\text{Pr}_3)_2]$ **1** (Fig. 1, see ESI† for details).

Complex **1** is the first near-linear f-element complex, with an N-Sm-N angle of $175.52(18)^\circ$ in the solid state (Fig. 2, see ESI† for details); this near-linearity contrasts with the bent C-Ln-C angles of $[\text{Ln}^{\text{II}}\{\text{C}(\text{SiMe}_3)_3\}_2]$ complexes (Ln = Sm, Yb, Eu).¹⁸⁻²⁰ The

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Fig. 1 Synthetic route to **1**.





Fig. 2 Molecular structure of **1**. Hydrogen atoms omitted for clarity. Selected bond lengths (Å) and angles ($^{\circ}$): Sm1–N1 2.483(6), Sm1–N2 2.483(6), Sm1...C7 3.180(8), Sm1...C16 3.169(8), Sm1...C19 3.082(8), Sm1...C34 3.224(8), N1–Sm1–N2 175.52(18), Sm1–N1–Si1 109.9(3), Sm1–N1–Si2 111.6(3), Si1–N1–Si2 138.5(4), Sm1–N2–Si3 109.8(4), Sm1–N2–Si4 110.8(3), Si3–N2–Si4 138.8(4).

bulky ^iPr groups are vital for the isolation of a homoleptic complex, as $[\text{Sm}\{\text{N}(\text{SiMe}_3)_2\}_2(\text{THF})_2]$ exhibits additional O-donors.²¹ The Sm–N distances in **1** [2.483(6) Å] are longer than those observed in $[\text{Sm}\{\text{N}(\text{SiMe}_3)_2\}_2(\text{THF})_2]$ [mean Sm–N 2.433(9) Å] but this is compensated by **1** exhibiting four short Sm...C_{methylene} distances [Sm...C 3.082(7)–3.224(7) Å] that are closer than the analogous Sm...C_{methyl} contacts observed in $[\text{Sm}\{\text{N}(\text{SiMe}_3)_2\}_2(\text{THF})_2]$ [Sm...C 3.32(1)–3.46(1) Å].²¹ The approximately planar SmNSi₂ fragments in **1** are staggered with respect to each other (twist angle of 44.42 $^{\circ}$), with the deviation from 90 $^{\circ}$ attributed to agostic Sm...C_{methylene} interactions.

Formally each nitrogen atom carries a single negative charge and the Sm^{II} ion is divalent, with an $[\text{Xe}]4f^6$ configuration. The f^6 configuration leads to a formally diamagnetic $^7\text{F}_0$ ground state, with close lying excited states that provide a non-zero magnetic moment at room temperature. Magnetic measurements on **1** give a room temperature magnetic moment of 3.62 μ_{B} that falls towards zero at low temperature (Fig. S2 and S3, ESI[†]). This is clearly incompatible with interesting low temperature magnetic behaviour. However, the structure of **1** is close to the ideal linear arrangement to stabilize the large angular momentum states of Dy^{III} and produce monstrous uniaxial magnetic anisotropy.

Such a Dy^{III} compound is challenging to make; we believe a route *via* the heteroleptic $[\text{Dy}\{\text{N}(\text{Si}^i\text{Pr}_3)_2\}_2\text{I}]$ treated with the potassium salt of a large anion might work through precipitation of a potassium iodide. Other routes can be imagined, and here we present predictions of the magnetic properties of such a complex, intending to inspire synthetic work towards the linear Dy^{III} complex, and, more ambitiously, the isoelectronic Tb^{III} analogue.

The properties of $[(^i\text{Pr}_3\text{Si})_2\text{N}-\text{Dy}-\text{N}(\text{Si}^i\text{Pr}_3)_2]^+$ **2** are predicted by CASSCF/RASSI/SINGLE_ANISO²² *ab initio* calculations (see ESI[†] for details) employing the structure of **1**, where Sm^{II} has been replaced by Dy^{III}. The validity of the method was tested by calculating the variable temperature magnetic behavior of **1**, where the agreement



Fig. 3 Electronic states and magnetic transition probabilities for the ground $^6\text{H}_{15/2}$ multiplet of **2** in zero field. The x-axis shows the magnetic moment of each state along the main magnetic axis of the molecule. Relaxation commences from the $| -15/2 \rangle$ state and only includes pathways which reverse the magnetization. Relaxation probabilities are calculated based on a magnetic perturbation and are normalized from each departing state (see ESI[†] for details).

is excellent (Fig. S2 and S3, ESI[†]). Dy^{III} has a $^6\text{H}_{15/2}$ ground multiplet, which is split by the crystal field into eight Kramer's doublets with total angular momentum projections $m_j = \pm 1/2, \pm 3/2, \dots, \pm 15/2$. The *ab initio* calculations show that the lowest six Kramer's doublets are the almost pure m_j states of $m_j = \pm 15/2, \pm 13/2, \pm 11/2, \pm 9/2, \pm 7/2$ and $\pm 5/2$, sharing a common quantization axis (Fig. 3 and Tables S1 and S2, ESI[†]). The two most energetic doublets are strongly mixed; a characteristic of low symmetry complexes due to the lack of a rigorous molecular C_{∞} axis.¹⁴ Along the main magnetic axis these two states can be expressed as $|\psi_{ab}\rangle = 64\%|\pm 3/2\rangle + 26\%|\mp 1/2\rangle$ and $|\psi_{cd}\rangle = 68\%|\pm 1/2\rangle + 31\%|\mp 3/2\rangle$ and (Table S2, ESI[†]), giving the most energetic Kramer's doublet a large g_y value of ~ 17.5 perpendicular to the main magnetic axis.

Magnetic relaxation in lanthanides follows three possible routes: (1) QTM within the ground doublet (e.g. $| -15/2 \rangle \rightarrow | +15/2 \rangle$ in Fig. 3), (2) thermally assisted QTM (TA-QTM) *via* excited states (e.g. $| -15/2 \rangle \rightarrow | -13/2 \rangle \rightarrow | +13/2 \rangle \rightarrow | +15/2 \rangle$), or (3) an Orbach process composed of direct and/or Raman mechanisms (e.g. $| -15/2 \rangle \rightarrow | -13/2 \rangle \rightarrow | +15/2 \rangle$). The most probable pathway depends on the composition of the states involved and their interactions with phonons. For example, the slow magnetic relaxation for $\{\text{Dy}_4\text{K}_2\}$ was shown to occur *via* the first or second excited states (TA-QTM), depending on the number and location of neighboring Dy^{III} ions providing a source of transverse magnetic field.⁷ The states with opposing magnetic projections are mixed proportionally to the product of the transverse field and the transverse g -factors and therefore TA-QTM will occur *via* the excited state which has transverse



g -factors above a certain threshold or where its main magnetic axis is non-collinear with that of the ground state. All non-QTM transitions are induced by the vibrational modes of the lattice (phonons) which create local oscillating magnetic fields through modulation of dipolar fields as well as an oscillating crystal field potential.²³ To a first approximation, we can associate the probability of a phonon induced transition with the average magnetic^{13,14,24} and crystal field perturbation matrix elements (see ESI† for details).

Compared to all known Dy^{III} complexes the calculated properties for **2** are unique with very small transverse g -factors and a common principal axis for the lowest six Kramers doublets. This suggests that both the probability of QTM within the ground doublet and TA-QTM is vanishingly small until the two most energetic doublets. Orbach relaxation is also strongly disfavoured in the low lying states as magnetic transition probabilities due to phonons are miniscule (Fig. 3). Efficient magnetic relaxation will only occur *via* the highest energy doublets (Fig. 3, Fig. S4 and Tables S4 and S5, ESI†). Therefore the *ab initio* calculation predicts $U_{\text{eff}} \approx 1800 \text{ cm}^{-1}$ for **2** – far greater than any complex to date. Whilst such calculations may over-estimate the energies of the crystal field states,^{25,26} we can predict a T_{B} in excess of 77 K as such temperatures are often around 1/20th of the U_{eff} value if QTM within the ground doublet is disfavoured, *e.g.* the $T_{\text{B}}/U_{\text{eff}}$ ratios for {Tb₂N₂^{3-•}}, {Mn₁₂} and {Mn₆} are approximately 1/16, 1/15 and 1/13 cm⁻¹ K⁻¹, respectively. Calculations for the Tb^{II} analogue **3**, which is also a 4f⁹ ion, predict analogous behavior to **2** (Table S6, ESI†). The high local symmetry at the Dy^{III} site implies that the nuclear quadrupole and hyperfine interactions will be axially symmetric, preventing efficient QTM within the lower energy doublets.

To examine the stability of **2**, we have performed *ab initio* calculations for modified geometries where the N–Dy–N angle and the Dy–N bond lengths have been altered by $\pm 0.5^\circ$ and $\pm 0.01 \text{ \AA}$, respectively (Fig. S5, ESI†). The results show that **2** is stabilized when the Dy–N bond length is shortened and the N–Dy–N angle is closer to 180° compared to **1**, yielding more favorable electronic properties. These calculations do not take into account the inclusion of a counter-ion in the structure, which may have consequences for crystal packing and the local structure of **2**.

Compound **1** is the first near-linear bis(amide) 4f-block complex. It allows us to propose a blueprint for the first generation of ‘high-temperature’ SMMs, with blocking temperatures exceeding that of liquid N₂ (77 K). The synthesis of the proposed archetypes, *viz.* the Dy^{III} and Tb^{III} analogues of **1**, is currently underway in our laboratory, however we believe this is a target many other groups should be pursuing. Calculations on other f^{*n*} ions suggest that f⁹ is ideal; even for the oblate f⁸ Tb^{III} analogue, **4**, we find that the pseudo-doublets show strong mixing between the $| -m_j \rangle$ and $| +m_j \rangle$ projections, (Tables S7 and S8, ESI†), which would lead to strong zero-field QTM.

While **2** would have a huge U_{eff} , an even higher U_{eff} barrier might be possible if dianionic monodentate ligands could be incorporated, *e.g.* [(Pr₃Si)₂C–Dy–C(Si⁺Pr₃)₂][–], containing dianionic methanediides. Our preliminary results suggest this could raise U_{eff} by a factor of 1.2 to 1.3. The incredible advances made in low coordination number metal–organic compounds in the last decade

suggest that such hypothetical complexes are now chemically feasible. These metal–organic compounds are becoming of great importance in molecular magnetism.^{8,10,27,28}

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